

## SWITCHMODE SERIES NPN SILICON TRANSISTORS

...designed for high-voltage, high-speed, power switching in inductive circuits where fall time is critical, They are particularly suited for line operated switchmode applications such as:

- \* Switching Regulators
  - \* Inverters
  - \* Solenoid and relay drivers
  - \* Motor Controls
  - \* Deflection Circuits
- Fast Turn-off Times

400ns Inductive Fall Time  $-25^{\circ}\text{C}$  (Typ)

2.5  $\mu\text{s}$  Inductive Storage Time  $-25^{\circ}\text{C}$  (Typ)

Operating Temperature Range  $-65^{\circ}\text{C}$  to  $+200^{\circ}\text{C}$

100 $^{\circ}\text{C}$  performance Specified for:

Reversed Biased SOA with Inductive Loads

Switching Times with Inductive Loads

Leakage Currents

**NPN**  
**MJ13332**  
**MJ13333**  
**MJ13334**  
**MJ13335**

**20 AMPERES**  
**POWER TRANSISTOR**  
**NPN SILICON**

**350-500 VOLTS**  
**175 WATTS**



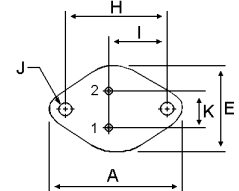
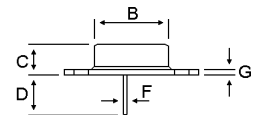
**TO-3**

### MAXIMUM RATINGS

Rating	Symbol	MJ13332	MJ13333	MJ13334	MJ13335	Unit
Collector-Emitter Voltage	$V_{CEV}$	650	700	750	800	V
Collector-Emitter Voltage	$V_{CEO}$	350	400	450	500	V
Emitter-Base Voltage	$V_{EB}$	6.0				V
Collector Current-Continuous	$I_C$	20				A
Peak	$I_{CM}$	30				A
Base Current	$I_B$	10				A
Total Device Dissipation @ $T_C=25^{\circ}\text{C}$	$P_D$	275				Watts
Derate above $25^{\circ}\text{C}$		1.0				$\text{W}/^{\circ}\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	$-65$ to $+200$				$^{\circ}\text{C}$

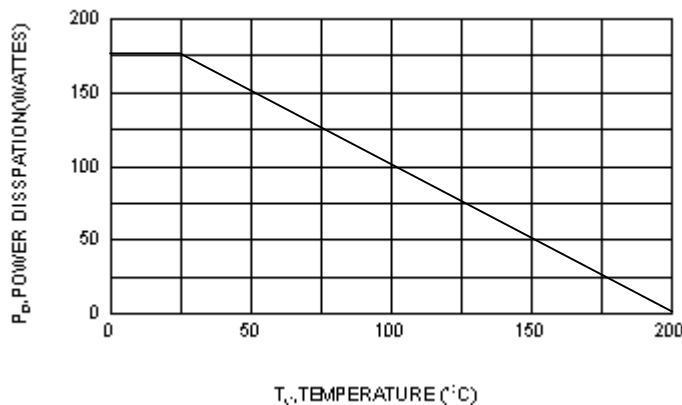
### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance to Case	$R_{\theta JC}$	1.0	$^{\circ}\text{C}/\text{W}$



PIN 1 BASE  
2 EMITTER  
COLLECTOR(CASE)

FIGURE -1 POWER DERATING



DIM	MILLIMETERS	
	MIN	MAX
A	38.75	39.96
B	19.28	22.23
C	7.96	9.28
D	11.18	12.19
E	25.20	26.67
F	0.92	1.09
G	1.38	1.62
H	29.90	30.40
I	16.64	17.30
J	3.88	4.36
K	10.67	11.18

**ELECTRICAL CHARACTERISTICS (T<sub>c</sub>=25°C unless otherwise noted)**

Characteristic	Symbol	Min.	Typ.	Max	Unit
----------------	--------	------	------	-----	------

**OFF CHARACTERISTICS**

Collector-Emitter Sustaining Voltage ( I <sub>c</sub> = 100 mA <sub>dc</sub> , I <sub>B</sub> = 0 )	MJ13332 MJ13333 MJ13334 MJ13335	V <sub>CEO(sus)</sub>	350 400 450 500	-- -- -- --	-- -- -- --	V
Collector Current ( V <sub>CE</sub> = Rated V <sub>CEV</sub> , V <sub>BE(off)</sub> = 1.5V )		I <sub>CEV</sub>	--	--	5.0	mA <sub>dc</sub>
Emitter Cutoff Current ( V <sub>BE</sub> = 6.0 V <sub>dc</sub> , I <sub>c</sub> = 0 )		I <sub>EBO</sub>	--	--	1.0	mA <sub>dc</sub>

**ON CHARACTERISTICS(1)**

DC current gain ( I <sub>c</sub> = 5.0 A <sub>dc</sub> , V <sub>CE</sub> = 5.0 V <sub>dc</sub> )		h <sub>FE</sub>	10	--	60	
Collector-Emitter Saturation Voltage ( I <sub>c</sub> = 10 A <sub>dc</sub> , I <sub>B</sub> = 2.0 A <sub>dc</sub> ) ( I <sub>c</sub> = 20 A <sub>dc</sub> , I <sub>B</sub> = 6.7 A <sub>dc</sub> )		V <sub>CE(sat)</sub>	-- --	-- --	1.8 5.0	V <sub>dc</sub>
Base-Emitter Saturation Voltage ( I <sub>c</sub> = 10 A <sub>dc</sub> , I <sub>B</sub> = 2.0 A <sub>dc</sub> )		V <sub>BE(sat)</sub>	--	--	1.8	V <sub>dc</sub>

**DYNAMIC CHARACTERISTICS**

Output Capacitance ( V <sub>CB</sub> = 10 V <sub>dc</sub> , I <sub>E</sub> = 0 , f=1.0 KHz )		C <sub>ob</sub>	125	--	500	pF
---	--	-----------------	-----	----	-----	----

**SWITCHING CHARACTERISTICS**

Delay time	V <sub>cc</sub> =250V, I <sub>c</sub> =10A I <sub>B1</sub> =2.0A, V <sub>BE</sub> =5.0V, t <sub>p</sub> =10us Duty Cycle 2.0%	t <sub>d</sub>	--	--	0.1	μs
Rise Time		t <sub>r</sub>	--	--	0.7	μs
Storage Time		t <sub>s</sub>	--	--	4.0	μs
Fall Time		t <sub>f</sub>	--	--	0.7	μs

(1) Pulse test: Pulse Width=300 s, Duty Cycle 2.0%

## Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life ( atomic energy control, aeronautics , traffic control, combustion control, safety devices etc.)